

v01.0402

HMC291

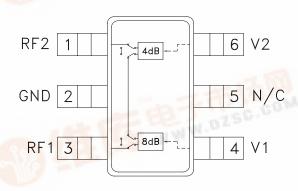
4 dB LSB GaAs MMIC 2-BIT DIGITAL ATTENUATOR, 0.7 - 4.0 GHz

Typical Applications

The HMC291 is ideal for:

- Cellular
- PCS, ISM, MMDS
- WLL Handset & Base Station

Functional Diagram



Features

4 dB LSB Steps to 12 dB
Single Positive Control Per BIT, 0/+3V
+/-0.2 dB Typical Bit Error
Miniature SOT 26 Package: 9 mm²

General Description

The HMC291 is a broadband 2 - bit positive control GaAs IC digital attenuator in a 6 lead SOT26 surface mount plastic package. Covering 0.7 to 4 GHz, the insertion loss is typically less than 0.7 to 1.3 dB. The attenuator bit values are 4 (LSB) and 8 dB for a total attenuation of 12 dB. Accuracy is excellent at \pm 0.2 dB typical with an IIP3 of up to +54 dBm. Two bit control voltage inputs, toggled between 0 and +3 to +5 volts, are used to select each attenuation state at less than 50 uA each. A single Vdd bias of +3 to +5 volts applied through an external 5K Ohm resistor is required.

Electrical Specifications,

 $T_{A} = +25^{\circ}$ C, Vdd = +3V to +5V & Vctl = 0/Vdd (Unless Otherwise Stated)

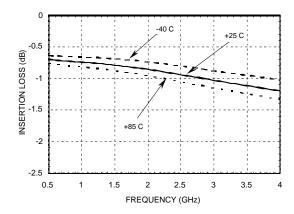
Parameter	DPA	Frequency	Min.	Typical	Max.	Units
Insertion Loss	0.00	0.7 - 1.4 GHz		0.7	1.0	dB
		1.4 - 2.3 GHz		0.9	1.3	dB
		2.3 - 2.7 GHz		1.0	1.4	dB
192		2.7 - 4.0 GHz		1.1	1.6	dB
Attenuation Range		0.7 - 4.0 GHz		12		dB
Return Loss (RF1 & RF2, All Atten. States)		0.7 - 1.4 GHz	14	17	- TV	dB
,		1.4 - 4.0 GHz	16	22	M.075	dB
Attenuation Accuracy: (Referenced to Insertion Loss)			413	- M. Au		
All Attenuation States	-T 1670	0.7 - 1.4 GHz	± 0.3 + 3°	% of Atten. Se	tting Max	dB
All Attenuation States	77.17	1.4 - 2.3 GHz	± 0.2 + 29	% of Atten. Set	tting Max	dB
All Attenuation States	- 69.56	2.3 - 2.7 GHz	± 0.2 + 39	% of Atten. Se	tting Max	dB
All Attenuation States	C.COM	2.7 - 4.0 GHz	± 0.4 + 59	% of Atten. Set	tting Max	dB
Input Power for 0.1 dB Compression	5V	0.7 - 4.0 GHz		26		dBm
190 7 4 - 41	3V			22		dBm
Input Third Order Intercept Point	5V	0.7 - 4.0 GHz		54		dBm
(Two-tone Input Power = 0 dBm Each Tone)	3V			50		dBm
Switching Characteristics		0.7 - 4.0 GHz				
tRISE_tFALL (10/90% RF)				560		ns
ON, tOFF (50% CTL to 10/90% RF)				600		ns



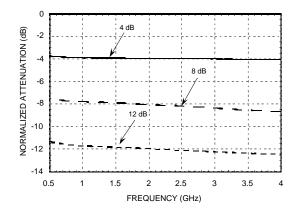


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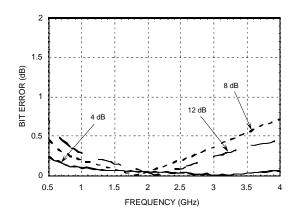
Insertion Loss



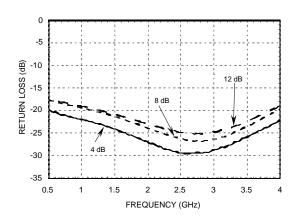
Normalized Attenuation



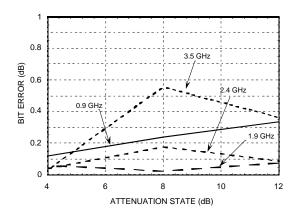
Absolute Bit Error vs. Frequency



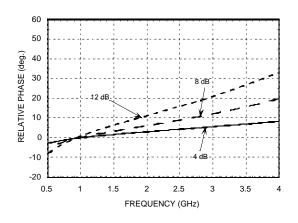
Return Loss RF1, RF2



Absolute Bit Error vs. Attenuation State



Relative Phase vs. Frequency



Note: All Data Typical Over Voltage (+3V to +5V) & Temperature (-40 to +85 deg. C.).



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Truth Table

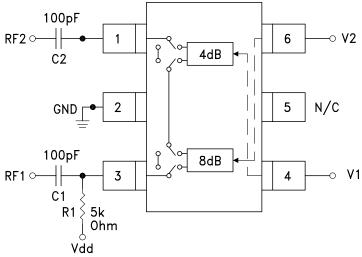
Control Voltage Input		Attenuation	
V1 8 dB	V2 4 dB	Setting RF1 - RF2	
High	High	Reference I.L.	
High	Low	4 dB	
Low	High	8 dB	
Low	Low	12 dB Max. Atten.	

Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.

Control & Bias Voltages

State	Bias Condition
Low	0 to +0.2V @ 20 uA Max.
High	Vdd ± 0.2V @ 50 uA Max.
Note: Vdd = +3V to 5V ± 0.2V	

Application Circuit



DC blocking capacitors C1 & C2 are required on RF1 & RF2. Choose C1 = $C2 = 100 \sim 300$ pF to allow lowest customer specific frequency to pass with minimal loss. R1 = 5K Ohm is required to supply voltage to the circuit throught either PIN 3 or PIN 1.



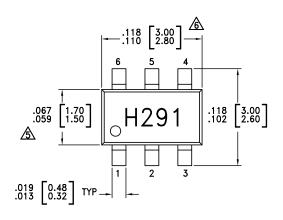
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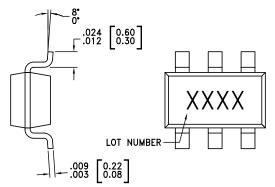
Absolute Maximum Ratings

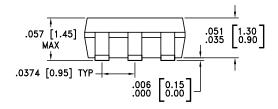
Control Voltage (V1, V2)	Vdd + 0.5 Vdc
Bias Voltage (Vdd)	+8.0 Vdc
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
RF Input Power (0.7 - 4 GHz)	+28 dBm

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Outline Drawing







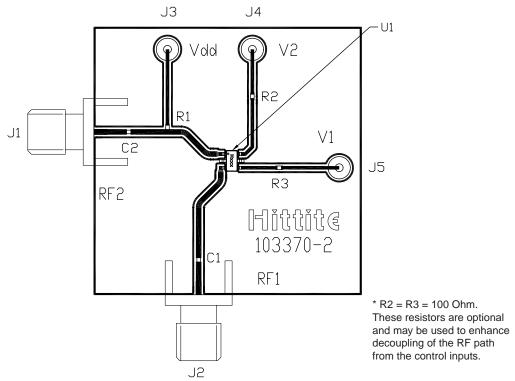
NOTES:

- 1. PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
- 2. LEADFRAME MATERIAL: COPPER ALLOY
- LEADFRAME PLATING: Sn/Pb SOLDER
- DIMENSIONS ARE IN INCHES [MILLIMETERS].
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- 6 DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 7. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.



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Evaluation Circuit Board



The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of VIA holes should be used to connect the top and bottom ground planes. The evaluation circuit board as shown is available from Hittite Microwave Corporation upon request.

List of Material

Item	Description	
J1 - J2	PC Mount SMA Connector	
J3 - J6	DC Pin	
R1	5k Ohm Resistor, 0402 Chip	
R2, R3	100 Ohm Resistor, 0402 Chip	
C1, C2	0402 Chip Capacitor, Select for Lowest Frequency of Operation	
U1	HMC291 Digital Attenuator	
PCB*	103370 Evaluation PCB 1.5" x 1.5"	
*Circuit Board Material Rogers 4350		





MICROWAVE CORPORATION

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Notes: